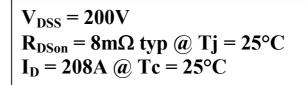
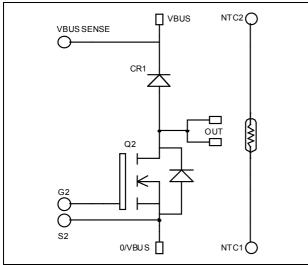


Boost chopper **MOSFET Power Module**





G2 🛭

S2 🛱

G2 0

OUT

NTC2

NTC1

O/VBUS

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

Absolute maximum ratings

0

VBUS

⋒ ∨BUS

| Symbol | Parameter | Max ratings | Unit | |
|-------------------|---|-------------------------------------|------|------|
| $V_{ m DSS}$ | Drain - Source Breakdown Voltage | | 200 | V |
| Ţ | Continuous Drain Current | $T_c = 25$ °C | 208 | |
| I_D | Continuous Drain Current | $T_c = 80^{\circ}C$ | 155 | A |
| I_{DM} | Pulsed Drain current | 832 | | |
| V_{GS} | Gate - Source Voltage | | ±30 | V |
| R _{DSon} | rain - Source ON Resistance | | 10 | mΩ |
| P_{D} | Maximum Power Dissipation | wer Dissipation $T_c = 25^{\circ}C$ | | W |
| I_{AR} | Avalanche current (repetitive and non repetitive) | | 100 | A |
| E_{AR} | Repetitive Avalanche Energy | | 50 | mJ |
| E_{AS} | Single Pulse Avalanche Energy | | 3000 | 1113 |

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | Min | Тур | Max | Unit |
|---------------------|---------------------------------|---|-----|-----|------|------|
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$ | | | 150 | μΑ |
| | | $V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$ | | | 750 | |
| R _{DS(on)} | Drain – Source on Resistance | $V_{GS} = 10V, I_D = 104A$ | | 8 | 10 | mΩ |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_D = 5mA$ | 3 | | 5 | V |
| I_{GSS} | Gate – Source Leakage Current | $V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$ | | | ±150 | nA |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | Min | Тур | Max | Unit |
|-----------------------------|------------------------------|--|-----|------|-----|------|
| C_{iss} | Input Capacitance | $V_{GS} = 0V$ | | 14.4 | | _ |
| C_{oss} | Output Capacitance | $V_{DS} = 25V$ | | 4.66 | | nF |
| C_{rss} | Reverse Transfer Capacitance | f = 1MHz | | 0.29 | | |
| Q_{g} | Total gate Charge | $V_{GS} = 10V$ | | 280 | | |
| Q_{gs} | Gate – Source Charge | $V_{Bus} = 100V$ | | 106 | | nC |
| Q_{gd} | Gate – Drain Charge | $I_D = 208A$ | | 134 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive switching @ 125°C $V_{GS} = 15V \\ V_{Bus} = 133V \\ I_D = 208A \\ R_G = 2.5\Omega$ | | 32 | | |
| $T_{\rm r}$ | Rise Time | | | 64 | | |
| $T_{d(off)}$ | Turn-off Delay Time | | | 88 | | ns |
| T_{f} | Fall Time | | | 116 | | |
| Eon | Turn-on Switching Energy | Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 133V$ $I_D = 208A$, $R_G = 2.5\Omega$ | | 1698 | | 1 |
| $\mathrm{E}_{\mathrm{off}}$ | Turn-off Switching Energy | | | 1858 | | μJ |
| Eon | Turn-on Switching Energy | Inductive switching @ 125°C $V_{GS} = 15V$, $V_{Bus} = 133V$ $I_D = 208A$, $R_G = 2.5\Omega$ | | 1872 | | |
| E _{off} | Turn-off Switching Energy | | | 1972 | | μJ |

Chopper diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|-----------------|---|-----------------------------------|----------------------|-----|-----|------|------|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | | 200 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | V _R =200V | $T_j = 25$ °C | | | 500 | μΑ |
| | | VR 200 V | $T_j = 125$ °C | | | 750 | μΑ |
| I_F | DC Forward Current | | $T_c = 80$ °C | | 180 | | A |
| | | $I_F = 180A$ | | | 1.1 | 1.15 | |
| $V_{\rm F}$ | Diode Forward Voltage | $I_F = 360A$ | | | 1.4 | | V |
| | | $I_F = 180A$ | $T_j = 125^{\circ}C$ | | 0.9 | | |
| t _{rr} | Reverse Recovery Time | $I_F = 180A$ $T_j = 125^{\circ}$ | $T_j = 25^{\circ}C$ | | 31 | | ns |
| | | | $T_j = 125$ °C | | 60 | | 115 |
| Q _{rr} | Reverse Recovery Charge | $V_R = 133V$ $di/dt = 600A/\mu s$ | $T_j = 25$ °C | | 180 | | пC |
| | | | $T_j = 125$ °C | | 750 | | iiC |



Thermal and package characteristics

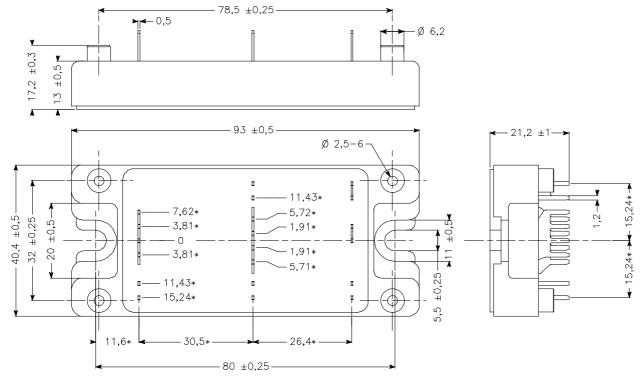
| Symbol | Characteristic | | | Min | Тур | Max | Unit |
|-------------------|---|-------------|------------|------|-----|------|------|
| R_{thJC} | Junction to Case Thermal Resistance | | Transistor | | 0 | 0.16 | °C/W |
| | | | Diode | | | 0.32 | |
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | | 4000 | | | V |
| T_{J} | Operating junction temperature range | | | -40 | | 150 | |
| T_{STG} | Storage Temperature Range | | -40 | | 125 | °C | |
| $T_{\rm C}$ | Operating Case Temperature | | | -40 | | 100 | |
| Torque | Mounting torque | To Heatsink | M5 | 2.5 | • | 4.7 | N.m |
| Wt | Package Weight | | | • | 160 | g | |

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

| Symbol | Characteristic | Min | Тур | Max | Unit | |
|------------------|-----------------------------|-----|------|-----|------|---|
| R ₂₅ | Resistance @ 25°C | | 50 | | kΩ | ĺ |
| ${ m B}_{25/85}$ | $T_{25} = 298.15 \text{ K}$ | | 3952 | | K | ĺ |

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

SP4 Package outline (dimensions in mm)

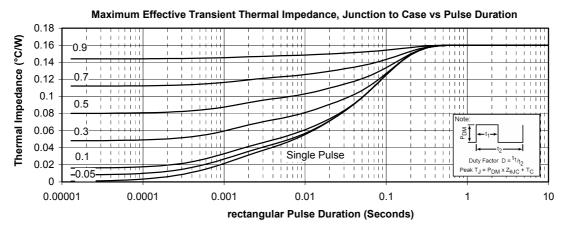


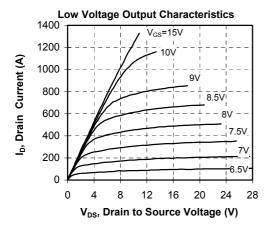
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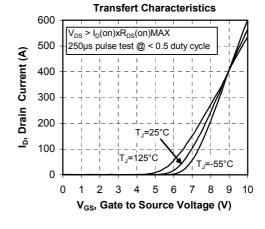
 $See \ application \ note \ APT0501 \ - \ Mounting \ Instructions \ for \ SP4 \ Power \ Modules \ on \ www.microsemi.com$

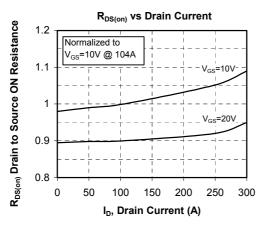


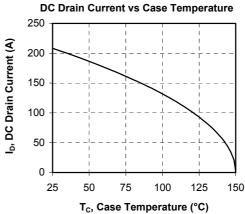
Typical Performance Curve





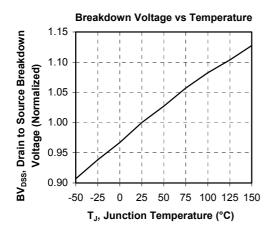


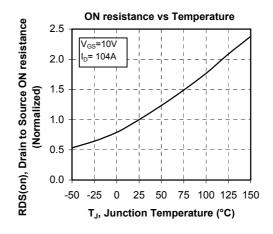


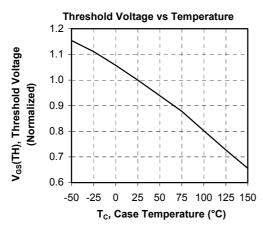


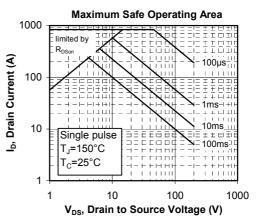
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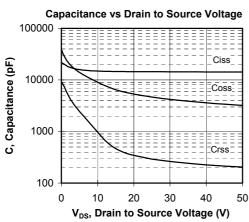


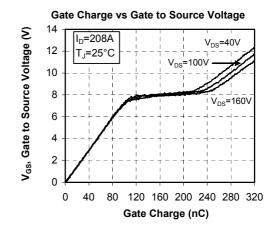




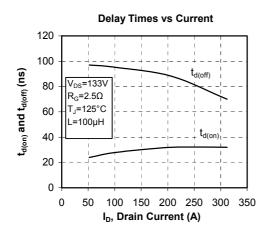


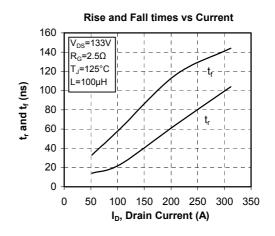


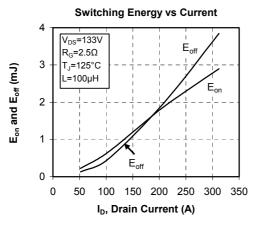


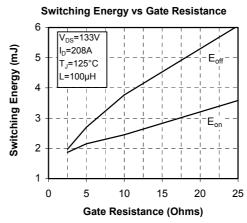


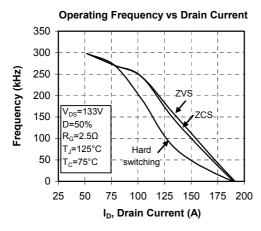


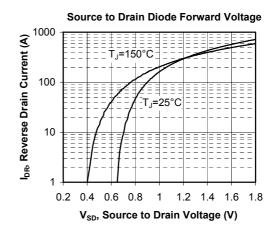












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